



### Vishay General Semiconductor

# **High Current Density Surface Mount Schottky Barrier Rectifiers**

# eSMP™ Series

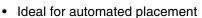


DO-220AA (SMP)

| MAJOR RATINGS AND CHARACTERISTICS |                |  |  |  |
|-----------------------------------|----------------|--|--|--|
| I <sub>F(AV)</sub>                | 1 A            |  |  |  |
| $V_{RRM}$                         | 30 V, 40 V     |  |  |  |
| I <sub>FSM</sub>                  | 30 A           |  |  |  |
| E <sub>AS</sub>                   | 10 mJ          |  |  |  |
| V <sub>F</sub>                    | 0.40 V, 0.45 V |  |  |  |
| T <sub>j</sub> max.               | 150 °C         |  |  |  |

#### **FEATURES**

• Very low profile - typical height of 1.0 mm



- Low forward voltage drop, low power losses
- · High efficiency
- · Low thermal resistance
- Meets MSL level 1, per J-STD-020C, LF max peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

(Note: These devices are not Q101 qualified.)

#### **MECHANICAL DATA**

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002B and JESD22-B102D E3 suffix for commercial grade

Polarity: Color band denotes the cathode end

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)                               |                                   |               |       |      |
|--|-----------------------------------|---------------|-------|------|
| PARAMETER  | SYMBOL                            | SS1P3         | SS1P4 | UNIT |
| Device marking code  |                                   | 13            | 14    |      |
| Maximum repetitive peak reverse voltage  | $V_{RRM}$                         | 30            | 40    | V    |
| Maximum average forward rectified current (see Fig. 1)   | I <sub>F(AV)</sub>                | 1.0           |       | Α    |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load                    | I <sub>FSM</sub>                  | 30            |       | А    |
| Non-repetitive avalanche energy at $I_{AS} = 1.5 \text{ A}$ , L = 10 mH, $T_j = 25 ^{\circ}\text{C}$ | E <sub>AS</sub>                   | 10            |       | mJ   |
| Voltage rate of change (rated V <sub>R</sub> )   | dv/dt                             | 10000         |       | V/µs |
| Operating junction and storage temperature range   | T <sub>J</sub> , T <sub>STG</sub> | - 55 to + 150 |       | °C   |

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### SS1P3 & SS1P4

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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |   |                |              |              |          |
|---|---|----------------|--------------|--------------|----------|
| PARAMETER   | TEST CONDITIONS   | SYMBOL         | SS1P3        | SS1P4        | UNIT     |
| Maximum instantaneous forward voltage <sup>(1)</sup>                              | at $I_F = 1.0 \text{ A}$ , $T_j = 25 ^{\circ}\text{C}$<br>at $I_F = 1.0 \text{ A}$ , $T_j = 125 ^{\circ}\text{C}$ | V <sub>F</sub> | 0.50<br>0.40 | 0.53<br>0.45 | V        |
| Maximum reverse current at rated $V_R^{(1)}$                                      | T <sub>j</sub> = 25 °C<br>T <sub>j</sub> = 125 °C   | I <sub>R</sub> | 150<br>15    |              | μA<br>mA |
| Typical junction capacitance  | at 4.0 V, 1 MHz   | $C_J$          | 70           |              | pF       |

#### Note:

(1) Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |  |                 |       |      |
|---|--|-----------------|-------|------|
| PARAMETER   | SYMBOL   | SS1P3           | SS1P4 | UNIT |
| Typical thermal resistance <sup>(1)</sup>                               | R <sub>θJA</sub><br>R <sub>θJL</sub><br>R <sub>θJC</sub> | 105<br>15<br>25 |       | °C/W |

#### Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas  $R_{\theta JC}$  is measured at the terminal of cathode band.  $R_{\theta JC}$  is measured at the top centre of the body

| ORDERING INFORMATION (Example) |                 |                        |               |                                  |  |
|--------------------------------|-----------------|------------------------|---------------|----------------------------------|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                    |  |
| SS1P3-E3/84A                   | 0.024           | 84A                    | 3000          | 7" Diameter Plastic Tape & Reel  |  |
| SS1P3-E3/85A                   | 0.024           | 85A                    | 10000         | 13" Diameter Plastic Tape & Reel |  |

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

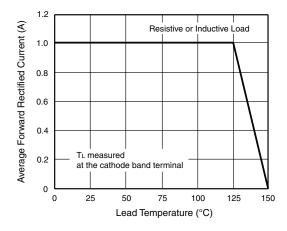


Figure 1. Maximum Forward Current Derating Curve

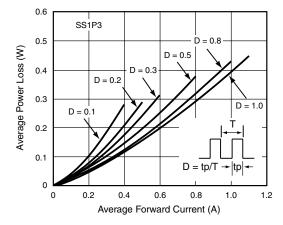


Figure 2. Forward Power Loss Characteristics





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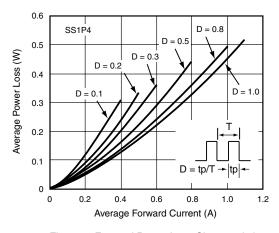


Figure 3. Forward Power Loss Characteristics

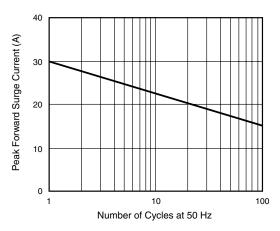


Figure 4. Typical Instantaneous Forward Characteristics

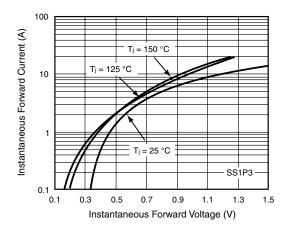


Figure 5. Typical Instantaneous Forward Characteristics

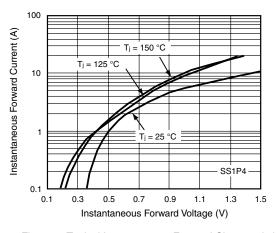


Figure 6. Typical Instantaneous Forward Characteristics

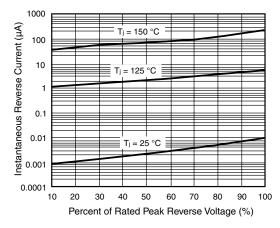


Figure 7. Typical Reverse Leakage Characteristics

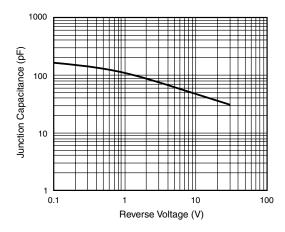


Figure 8. Typical Junction Capacitance

### SS1P3 & SS1P4

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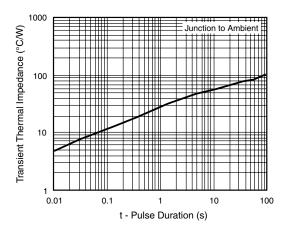


Figure 9. Typical Transient Thermal Impedatnce

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### DO-220AA (SMP) - 0.012 (0.30) REF Cathode band 0.053 (1.35) 0.036 (0.91) 0.086 (2.18) 0.024 (0.61) 0.041 (1.05) 0.074 (1.88) 0.032 (0.80) 0.103 (2.60) 0.142 (3.61) 0.016 (0.40) 0.087 (2.20) 0.126 (3.19) 0.158 (4.00) 0.146 (3.70) 0.030 0.105 0.025 (0.762)(2.67) 0.013 (0.35) (0.635)↑ 0.045 (1.15) 0.004 (0.10) 0.033 (0.85) **♦** 0.050 0.100 0.012 (0.30) (1.27) <del>\</del> (2.54)0.000 (0.00) 0.018 (0.45) 0.006 (0.15)

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